# 74LVT244B; 74LVTH244B 3.3 V octal buffer/line driver; 3-state Rev. 4 — 14 June 2017

**Product data sheet** 

#### 1 **General description**

The 74LVT244B; 74LVTH244B is a high-performance BiCMOS product designed for V<sub>CC</sub> operation at 3.3 V.

This device is an octal buffer that is ideal for driving bus lines. The device features two output enable inputs (1OE and 2OE), each controlling four of the 3-state outputs.

#### Features and benefits

- · Octal bus interface
- 3-state buffers
- Speed upgrade of 74LVT244A
- Output capability: +64 mA and -32 mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5 V supply
- Bus hold data inputs eliminate need for external pull-up resistors to hold unused inputs
- Power-up 3-state
- Live insertion and extraction permitted
- No bus current loading when output is tied to 5 V bus
- Latch-up protection:
  - JESD78: exceeds 500 mA
- ESD protection:
  - HBM EIA/JESD22-A114-C exceeds 2000 V
  - MM EIA/JESD22-A115-A 200 V

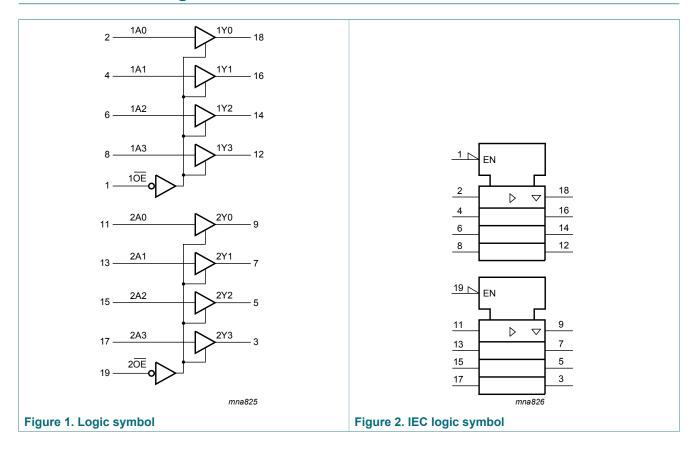
## **Ordering information**

**Table 1. Ordering information** 

Type number	Package								
	Temperature range	Name	Description	Version					
74LVT244BD	-40 °C to +85 °C	SO20	plastic small outline package; 20 leads;	SOT163-1					
74LVTH244BD			body width 7.5 mm						
74LVT244BDB	-40 °C to +85 °C	SSOP20	plastic shrink small outline package; 20 leads;	SOT339-1					
74LVTH244BDB			body width 5.3 mm						
74LVT244BPW	-40 °C to +85 °C	TSSOP20	plastic thin shrink small outline package; 20 leads;	SOT360-1					
74LVTH244BPW			body width 4.4 mm						

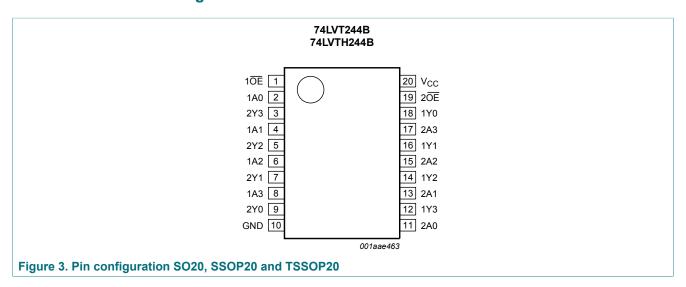


# 4 Functional diagram



## 5 Pinning information

## 5.1 Pinning



#### 5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
1 <del>OE</del> , 2 <del>OE</del>	1, 19	output enable input (active low)
1A0, 1A1, 1A2, 1A3	2, 4, 6, 8	data input
2Y0, 2Y1, 2Y2, 2Y3	9, 7, 5, 3	data output
GND	10	ground (0 V)
2A0, 2A1, 2A2, 2A3	11, 13, 15, 17	data input
1Y0, 1Y1, 1Y2, 1Y3	18, 16, 14, 12	data output
V <sub>CC</sub>	20	supply voltage

## 6 Functional description

Table 3. Function table [1]

Table 6.1 allotter table								
Control	Input	Output						
nOE	nAn	nYn						
L	L	L						
L	Н	Н						
Н	X	Z						

- [1] H = HIGH voltage level;
  - L = LOW voltage level;
  - X = don't care;
  - Z = high-impedance OFF-state.

74LVT\_LVTH244B

All information provided in this document is subject to legal disclaimers.

## 7 Limiting values

#### **Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Parameter	Conditions	Min	Max	Unit
supply voltage		-0.5	+4.6	V
input voltage	[1]	-0.5	+7.0	V
output voltage	output in OFF-state or HIGH-state [1]	-0.5	+7.0	V
input clamping current	V <sub>I</sub> < 0 V	-50	-	mA
output clamping current	V <sub>O</sub> < 0 V	-50	-	mA
output current	output in LOW-state	-	128	mA
	output in HIGH-state	-64	-	mA
storage temperature		-65	+150	°C
junction temperature	[2]	-	150	°C
total power dissipation	$T_{amb} = -40 \text{ to } +85 \text{ °C}$ [3]	-	500	mW
	supply voltage input voltage output voltage input clamping current output clamping current output current storage temperature junction temperature	supply voltage       [1]         input voltage       output in OFF-state or HIGH-state         input clamping current $V_1 < 0 \text{ V}$ output clamping current $V_0 < 0 \text{ V}$ output current       output in LOW-state         output in HIGH-state       [2]	supply voltage       -0.5         input voltage       output in OFF-state or HIGH-state       [1] -0.5         output clamping current $V_1 < 0 \text{ V}$ -50         output clamping current $V_0 < 0 \text{ V}$ -50         output current       output in LOW-state       -         output in HIGH-state       -64         storage temperature       -65         junction temperature       [2] -	supply voltage-0.5+4.6input voltage[1]-0.5+7.0output voltageoutput in OFF-state or HIGH-state[1]-0.5+7.0input clamping current $V_1 < 0 \ V$ -50-output clamping current $V_0 < 0 \ V$ -50-output currentoutput in LOW-state-128output in HIGH-state-64-storage temperature-65+150junction temperature[2]-150

<sup>[1]</sup> The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

## 8 Recommended operating conditions

#### **Table 5. Operating conditions**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CC}$	supply voltage		2.7	-	3.6	V
VI	input voltage		0	-	5.5	V
I <sub>OH</sub>	HIGH-level output current		-32	-	-	mA
I <sub>OL</sub>	LOW-level output current	none	-	-	32	mA
		current duty cycle ≤ 50 %; f <sub>i</sub> ≥ 1 kHz	-	-	64	mA
T <sub>amb</sub>	ambient temperature	in free-air	-40	-	+85	°C
Δt/ΔV	input transition rise and fall rate	outputs enabled	-	-	10	ns/V

<sup>[2]</sup> The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability.

<sup>[3]</sup> For SO20 packages: above 70 °C derate linearly with 8 mW/K. For SSOP20 and TSSOP20 packages: above 60 °C derate linearly with 5.5 mW/K.

### 9 Static characteristics

#### **Table 6. Static characteristics**

At recommended operating conditions; Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ <sup>[1]</sup>	Max	Unit
T <sub>amb</sub> = -40	0 °C to +85 °C		<u> </u>		1	
V <sub>IK</sub>	input clamping voltage	V <sub>CC</sub> = 2.7 V; I <sub>IK</sub> = -18 mA	-1.2	-0.9	-	٧
V <sub>IH</sub>	HIGH-level input voltage		2.0	-	-	٧
V <sub>IL</sub>	LOW-level input voltage		-	-	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>CC</sub> = 2.7 V; I <sub>OH</sub> = -100 μA	V <sub>CC</sub> - 2.0	V <sub>CC</sub> - 2.1	-	V
		V <sub>CC</sub> = 2.7 V; I <sub>OH</sub> = -8 mA	2.4	2.5	-	V
		V <sub>CC</sub> = 3.0 V; I <sub>OH</sub> = -32 mA	2.0	2.2	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>CC</sub> = 2.7 V; I <sub>OL</sub> = 100 μA	-	0.1	0.2	V
		V <sub>CC</sub> = 2.7 V; I <sub>OL</sub> = 24 mA	-	0.3	0.5	V
		V <sub>CC</sub> = 3.0 V; I <sub>OL</sub> = 16 mA	-	0.25	0.4	V
		V <sub>CC</sub> = 3.0 V; I <sub>OL</sub> = 32 mA	-	0.3	0.5	V
		V <sub>CC</sub> = 3.0 V; I <sub>OL</sub> = 64 mA	-	0.4	0.55	V
I <sub>I</sub>	input leakage current	all input pins				
		V <sub>CC</sub> = 0 V or 3.6 V; V <sub>I</sub> = 5.5 V	-	0.1	10	μA
		control pins				
		$V_{CC}$ = 3.6 V; $V_I$ = $V_{CC}$ or GND	-1	±0.1	1	μA
		data pins	[2]			
		V <sub>CC</sub> = 3.6 V; V <sub>I</sub> = V <sub>CC</sub>	-	0.1	1	μA
		V <sub>CC</sub> = 3.6 V; V <sub>I</sub> = 0 V	-5	-1	-	μA
I <sub>OFF</sub>	power-off leakage current	$V_{CC} = 0 \text{ V}; V_{I} \text{ or } V_{O} = 0 \text{ V to } 4.5 \text{ V}$	-100	1	+100	μA
I <sub>BHL</sub>	bus hold LOW current	V <sub>CC</sub> = 3 V; V <sub>I</sub> = 0.8 V	75	130	-	μA
I <sub>BHH</sub>	bus hold HIGH current	V <sub>CC</sub> = 3 V; V <sub>I</sub> = 2.0 V	-	-140	-75	μA
I <sub>BHLO</sub>	bus hold LOW overdrive current	V <sub>CC</sub> = 3.6 V; V <sub>I</sub> = 0 V to 3.6 V	<sup>[3]</sup> 500	-	-	μA
I <sub>BHHO</sub>	bus hold HIGH overdrive current	V <sub>CC</sub> = 3.6 V; V <sub>I</sub> = 0 V to 3.6 V	-	-	-500	μA
I <sub>EX</sub>	external current	nYn output in HIGH-state when $V_O > V_{CC}$ ; $V_O = 5.5 \text{ V;} V_{CC} = 3.3 \text{ V}$	-	60	125	μΑ
I <sub>O(pu/pd)</sub>	power-up/power-down output current	$V_{CC} \le 1.2 \text{ V}; V_O = 0.5 \text{ V to } V_{CC};$ $V_I = \text{GND or } V_{CC}; n\overline{OE} = \text{don't care}$	<sup>[4]</sup> -100	±1	+100	μA
l <sub>OZ</sub>	OFF-state output current	$V_{CC}$ = 3.6 V; $V_I$ = $V_{IH}$ or $V_{IL}$				
		V <sub>O</sub> = 3.0 V	-	1	5	μΑ
		V <sub>O</sub> = 0.5 V	-5	-1	-	μA
I <sub>CC</sub>	supply current	$V_{CC} = 3.6 \text{ V}; V_{I} = \text{GND or } V_{CC}; I_{O} = 0 \text{ A}$				
		output HIGH	_	0.13	0.19	mA

74LVT\_LVTH244B

All information provided in this document is subject to legal disclaimers.

Symbol	Parameter	Conditions	Min	Typ <sup>[1]</sup>	Max	Unit
		output LOW	-	2	5	mA
		outputs disabled [5]	-	0.13	0.19	mA
ΔI <sub>CC</sub>	additional supply current	per input pin; $V_{CC}$ = 3.0 V to 3.6 V; one input at $V_{CC}$ - 0.6 V and other inputs at $V_{CC}$ or GND	-	0.1	0.2	mA
Cı	input capacitance	V <sub>I</sub> = 0 V or 3.0 V	-	4	-	pF
Co	output capacitance	outputs disabled; V <sub>O</sub> = 0 V or 3.0 V	-	8	-	pF

- Typical values are measured at  $T_{amb}$  = 25 °C.
- Unused pins at  $V_{\text{CC}}$  or GND.
- This is the bus hold overdrive current required to force the input to the opposite logic state.
- This parameter is valid for any  $V_{CC}$  between 0 V and 1.2 V with a transition time of up to 10 ms. From  $V_{CC}$  = 1.2 V to  $V_{CC}$  = 3.3 V ± 0.3 V a transition time of 100  $\mu$ s is permitted. This parameter is valid for  $T_{amb}$  = 25 °C only.
- $I_{CC}$  is measured with outputs pulled to  $V_{CC}$  or GND. This is the increase in supply current for each input at  $V_{CC}$  0.6 V.

## 10 Dynamic characteristics

#### **Table 7. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 6.

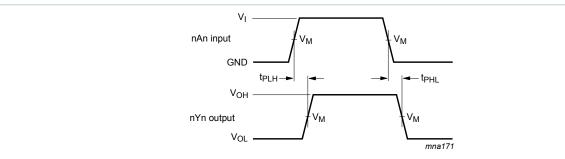
Symbol	Parameter	Conditions	Min	Typ <sup>[1]</sup>	Max	Unit
T <sub>amb</sub> = -40	0 °C to +85 °C					
t <sub>PLH</sub>	LOW to HIGH	nAn to nYn; see Figure 4				
	propagation delay	V <sub>CC</sub> = 2.7 V	-	-	3.8	ns
	propagation delay  HIL HIGH to LOW propagation delay  ZH OFF-state to HIGH propagation delay  ZL OFF-state to LOW propagation delay  HIGH to OFF-state propagation delay  LZ LOW to OFF-state	V <sub>CC</sub> = 3.0 V to 3.6 V	1.1	1.9	3.5	ns
t <sub>PHL</sub>		nAn to nYn; see Figure 4				
	propagation delay	V <sub>CC</sub> = 2.7 V	-	-	3.6	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.3	2.0	3.3	ns
1 411		nOE to nYn; see Figure 5				
		V <sub>CC</sub> = 2.7 V	-	-	5.3	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	3.6 1.3 2.0 3.3 5 5.3 1.1 2.8 4.5 5 4.9 1.4 2.3 4.4	4.5	ns	
t <sub>PZL</sub>	OFF-state to LOW	nOE to nYn; see Figure 5				
	propagation delay	V <sub>CC</sub> = 2.7 V	-	-	4.9	ns
	LOW to HIGH propagation delay  HIGH to LOW propagation delay  OFF-state to HIGH propagation delay  CL OFF-state to LOW propagation delay  HIGH to OFF-state propagation delay	V <sub>CC</sub> = 3.0 V to 3.6 V	1.4	2.3	4.4	ns
t <sub>PHZ</sub>		nOE to nYn; see Figure 5				
	propagation delay	V <sub>CC</sub> = 2.7 V	-	-	4.5	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.9	2.9	4.4	ns
t <sub>PLZ</sub>		nOE to nYn; see Figure 5				
	propagation delay	V <sub>CC</sub> = 2.7 V	-	-	4.4	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.8	2.5	4.4	ns

<sup>[1]</sup> Typical values are measured at  $V_{CC}$  = 3.3 V and  $T_{amb}$  = 25 °C.

74LVT\_LVTH244B

All information provided in this document is subject to legal disclaimers.

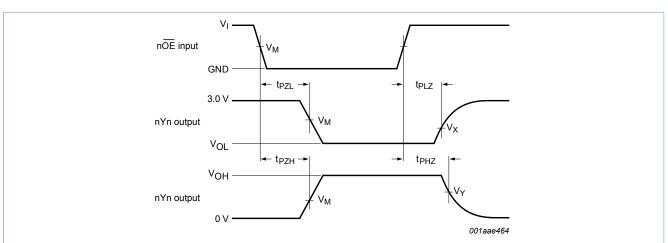
#### 10.1 Waveforms and test circuit



Measurement points are given in Table 8.

 $V_{\text{OL}}$  and  $V_{\text{OH}}$  are typical voltage output levels that occur with the output load.

Figure 4. Propagation delay input (nAn) to output (nYn)



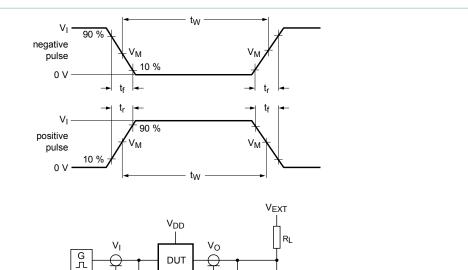
Measurement points are given in Table 8.

 $V_{\text{OL}}$  and  $V_{\text{OH}}$  are typical voltage output levels that occur with the output load.

Figure 5. 3-state output enable and disable times

**Table 8. Measurement points** 

Input	Output	Output					
V <sub>M</sub>	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>				
1.5 V	1.5 V	V <sub>OL</sub> + 0.3 V	V <sub>OH</sub> - 0.3 V				



001aai546

Test data is given in Table 9.

Definitions test circuit:

R<sub>L</sub> = Load resistance.

 $C_L$  = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance should be equal to output impedance  $Z_0$  of the pulse generator.

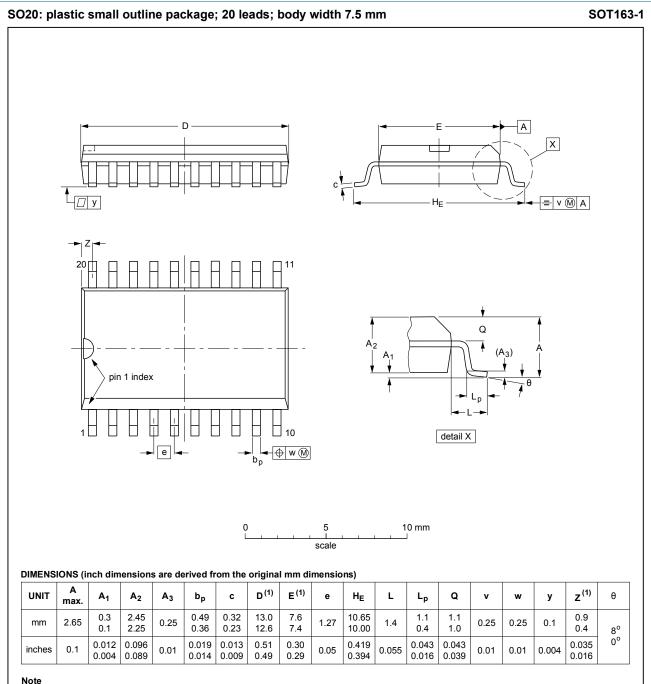
 $V_{EXT}$  = Test voltage for switching times.

Figure 6. Test circuit for measuring switching times

Table 9. Test data

Input			Load		V <sub>EXT</sub>			
VI	fi	t <sub>W</sub>	t <sub>r</sub> , t <sub>f</sub>	CL	R <sub>L</sub>	t <sub>PHZ</sub> , t <sub>PZH</sub>	t <sub>PLZ</sub> , t <sub>PZL</sub>	t <sub>PLH</sub> , t <sub>PHL</sub>
2.7 V	≤ 10 MHz	500 ns	≤ 2.5 ns	50 pF	500 Ω	GND	6 V	open

## 11 Package outline



#### Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE VERSION		REFER	EUROPEAN	ISSUE DATE		
	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT163-1	075E04	MS-013				<del>99-12-27</del> 03-02-19

Figure 7. Package outline SOT163-1 (SO20)

74LVT\_LVTH244B

All information provided in this document is subject to legal disclaimers.

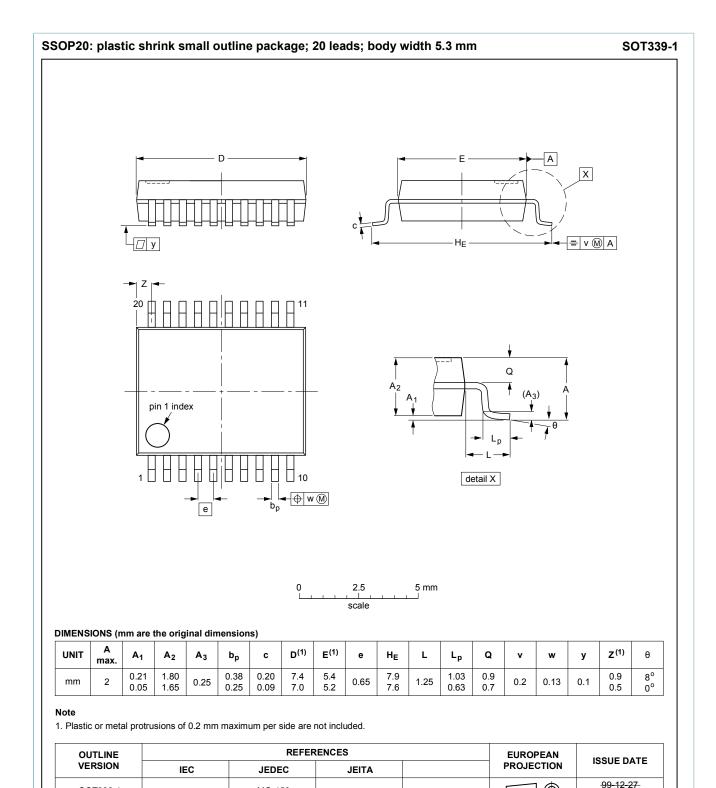


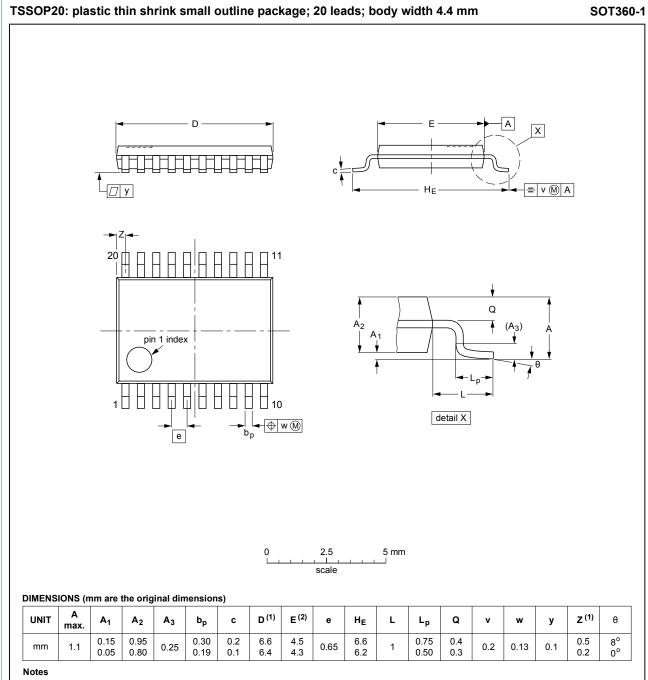
Figure 8. Package outline SOT339-1 (SSOP20)

MO-150

03-02-19

 $\bigoplus \bigoplus$ 

SOT339-1



- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFERENCES			EUROPEAN	ISSUE DATE
VERSION	IEC	IEC JEDEC JEITA		PROJECTION	ISSUE DATE	
SOT360-1		MO-153				<del>99-12-27</del> 03-02-19

Figure 9. Package outline SOT360-1 (TSSOP20)

74LVT\_LVTH244B

All information provided in this document is subject to legal disclaimers.

## 12 Abbreviations

#### Table 10. Abbreviations

Acronym	Description
BiCMOS	Bipolar Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

## 13 Revision history

#### **Table 11. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74LVT_LVTH244B v.4	20170614	Product data sheet	-	74LVT_LVTH244B v.3		
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>					
74LVT_LVTH244B v.3	20060303	Product data sheet	-	74LVT244B v.2		
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the new presentation and information standard of Philips Semiconductors.</li> <li>Section 3: Added type numbers 74LVTH244BD, 74LVTH244BDB and 74LVTH244BPW.</li> </ul>					
74LVT244B v.2	20030919	Product specification	-	74LVT244B v.1		
74LVT244B v.1	19981101	Product specification	-	-		

## 14 Legal information

#### 14.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- The term 'short data sheet' is explained in section "Definitions". [2] [3]
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nexperia.com.

#### 14.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Nexperia sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

**Product specification** — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Nexperia and its customer, unless Nexperia and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Nexperia product is deemed to offer functions and qualities beyond those described in the Product data sheet.

#### 14.3 Disclaimers

Limited warranty and liability - Information in this document is believed to be accurate and reliable. However, Nexperia does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Nexperia takes no responsibility for the content in this document if provided by an information source outside of Nexperia. In no event shall Nexperia be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory. Notwithstanding any damages that customer might incur for any reason whatsoever, Nexperia's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the Terms and conditions of commercial sale of Nexperia.

Right to make changes — Nexperia reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — Nexperia products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an Nexperia product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Nexperia and its suppliers accept no liability for inclusion and/or use of Nexperia products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. Nexperia makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification. Customers are responsible for the design and operation of their applications and products using Nexperia products, and Nexperia accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Nexperia product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products. Nexperia does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Nexperia products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Nexperia does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — Nexperia products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nexperia.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Nexperia hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Nexperia products by

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

All information provided in this document is subject to legal disclaimers.

Non-automotive qualified products — Unless this data sheet expressly states that this specific Nexperia product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. Nexperia accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications. In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without Nexperia's warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond Nexperia's specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies Nexperia for any liability, damages or failed product claims resulting from customer

design and use of the product for automotive applications beyond Nexperia's standard warranty and Nexperia's product specifications.

**Translations** — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

#### 14.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

# 74LVT244B; 74LVTH244B

3.3 V octal buffer/line driver; 3-state

#### **Contents**

1	General description	1
2	Features and benefits	
3	Ordering information	1
4	Functional diagram	2
5	Pinning information	
5.1	Pinning	3
5.2	Pin description	
6	Functional description	
7	Limiting values	
8	Recommended operating conditions	4
9	Static characteristics	
10	Dynamic characteristics	
10.1	Waveforms and test circuit	
11	Package outline	9
12	Abbreviations	
13	Revision history	
14	Legal information	

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.